

Product data sheet

1. General description

High voltage, high speed, planar passivated NPN power switching transistor with integrated anti-parallel E-C diode in a SOT78 (TO-220AB) plastic package.

2. Features and benefits

- · Low thermal resistance
- Fast switching
- High voltage capability
- Integrated anti-parallel E-C diode

3. Applications

- Integrated fluorescent lamp ballasts e.g. high power cluster lamps
- Low Voltage Tungsten Halogen transformers
- Remote fluorescent lamp ballasts
- Self Oscillating Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		7	00		V
I _C	collector current	DC; <u>Fig. 1; Fig. 2; Fig. 4</u>	4			А	
P _{tot}	total power dissipation	T _{mb} ≤ 25 °C; <u>Fig. 3</u>	75		W		
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics						
h _{FE}	DC current gain	I _C = 1.0 A; V _{CE} = 5 V; <u>Fig. 10</u>		12	20	40	
		I _c = 2.0 A; V _{ce} = 5 V; <u>Fig. 10</u>		10	17	28	

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	mb	с
2	С	collector	ן ך ⊖ ך	L L L
3	E	emitter		₿ ──Қ 本
mb	С	mounting base; connected to collector		E sym131

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PHD13005	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

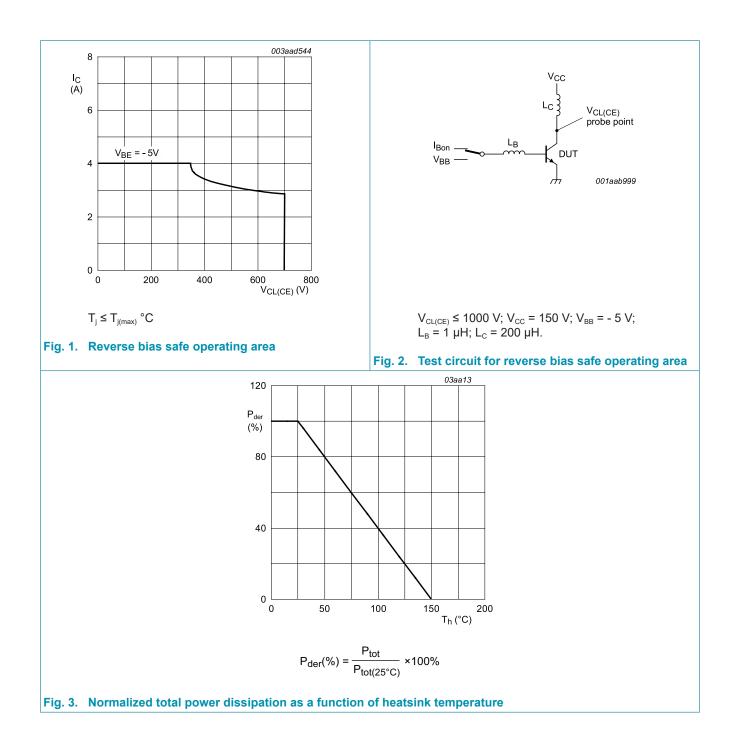
7. Limiting values

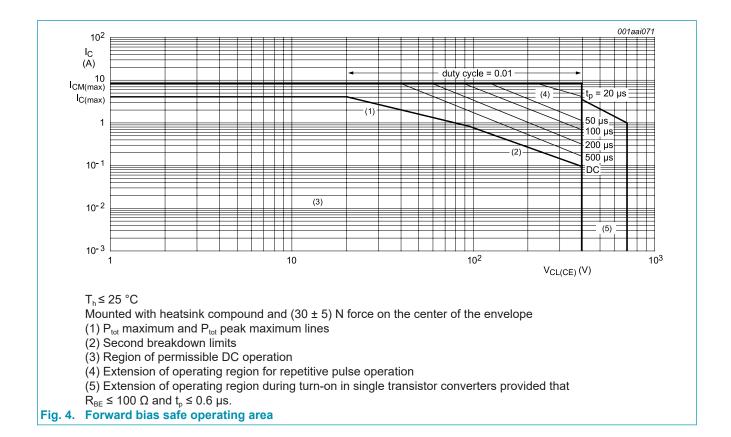
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V	700	V
V _{CBO}	collector-base voltage	I _E = 0 A	700	V
V _{CEO}	collector-emitter voltage	I _B = 0 A	400	V
I _c	collector current	DC; <u>Fig. 1; Fig. 2; Fig. 4</u>	4	А
I _{CM}	peak collector current	Fig. 1; Fig. 2; Fig. 4	8	А
I _B	base current	DC	2	А
I _{BM}	peak base current		4	А
P _{tot}	total power dissipation	T _{mb} ≤ 25 °C; <u>Fig. 3</u>	75	W
T _{stg}	storage temperature		-65 to 150	°C
T _j	junction temperature		150	°C

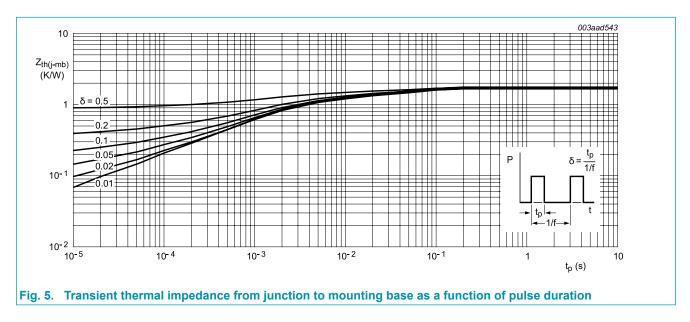
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	1.67	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W

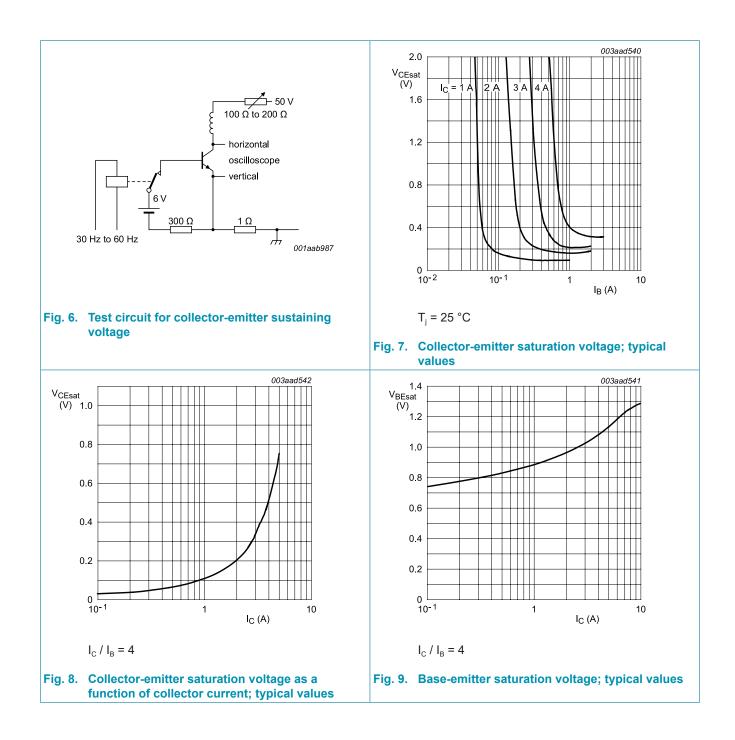


9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics	· · · · ·				
I _{CES}	collector-emitter cut-off	V _{BE} = 0 V; V _{CE} = 700 V; T _j = 100 °C; [1]	-	-	5	mA
	current	V _{BE} = 0 V; V _{CE} = 700 V; [1]	-	-	1	mA
I _{CBO}	collector-base cut-off current	V _{CB} = 700 V; I _E = 0 A; [1]	-	-	1	mA
I _{CEO}	collector-emitter cut-off current	V _{CE} = 400 V; I _B = 0 A; [1]	-	-	0.1	mA
I _{EBO}	emitter-base cut-off current	V _{EB} = 9 V; I _C = 0 A	-	-	10	mA
V_{CEOsus}	collector-emitter sustaining voltage			-	-	V
V _{CEsat}	collector-emitter	I _C = 1.0 A; I _B = 0.2 A; <u>Fig. 7; Fig. 8</u>	-	0.1	0.5	V
	saturation voltage	I _C = 2.0 A; I _B = 0.5 A; <u>Fig. 7; Fig. 8</u>	-	0.2	0.6	V
		I _c = 4.0 A; I _B = 1.0 A; <u>Fig. 7; Fig. 8</u>	-	0.3	1	V
V _{BEsat}	base-emitter saturation	$I_{\rm C} = 2.0 \text{ A}; I_{\rm B} = 0.5 \text{ A}; Fig. 9$	-	0.92	1.6	V
	voltage	$I_{c} = 1.0 \text{ A}; I_{B} = 0.2 \text{ A}; Fig. 9$	-	0.85	1.2	V
V _F	forward voltage	I _F = 2.0 A	-	1.04	1.5	V
h _{FE}	DC current gain	I _c = 1.0 A; V _{ce} = 5 V; <u>Fig. 10</u>	12	20	40	
		I _c = 2.0 A; V _{ce} = 5 V; <u>Fig. 10</u>	10	17	28	
Dynamic	characteristics	· · · · ·				
t _s	storage time	$I_{C} = 2.0 \text{ A}; I_{Bon} = 0.4 \text{ A}; V_{BB} = -5 \text{ V}; \\ L_{B} = 1 \mu\text{H}; \text{ inductive load}; \underline{\text{Fig. 11}}; \\ \underline{\text{Fig. 12}}$	-	1.2	2	μs
		$\begin{split} I_{C} &= 2.0 \text{ A}; I_{Bon} = 0.4 \text{ A}; I_{Boff} = -0.4 \text{ A}; \\ R_{L} &= 75 \Omega; \text{ resistive load}; \underline{Fig. 13}; \\ \hline \text{Fig. 14} \end{split}$	-	2.7	4	μs
		$\begin{split} I_{C} &= 2.0 \text{ A}; \ I_{Bon} = 0.4 \text{ A}; \ V_{BB} = -5 \text{ V}; \\ L_{B} &= 1 \ \mu\text{H}; \ T_{j} = 100 \ ^{\circ}\text{C}; \ \text{inductive load}; \\ \hline \text{Fig. 11}; \ \hline \text{Fig. 12} \end{split}$	-	1.4	4	μs
t _r	fall time	$I_{C} = 2.0 \text{ A}; I_{Bon} = 0.4 \text{ A}; I_{Boff} = -0.4 \text{ A}; R_{L} = 75 \Omega; \text{ resistive load}; \frac{\text{Fig. 13}}{\text{Fig. 14}};$	-	0.3	0.9	μs
		$ \begin{array}{l} I_{C} = 2.0 \text{ A}; \ I_{Bon} = 0.4 \text{ A}; \ V_{BB} = -5 \text{ V}; \\ L_{B} = 1 \ \mu\text{H}; \ T_{j} = 100 \ ^{\circ}\text{C}; \ \text{inductive load}; \\ \hline \text{Fig. 11}; \ \hline \text{Fig. 12} \end{array} $	-	0.16	0.9	μs
		$I_{c} = 2.0 \text{ A}; I_{Bon} = 0.4 \text{ A}; V_{BB} = -5 \text{ V};$ $L_{B} = 1 \mu\text{H}; \text{ inductive load}; \frac{\text{Fig. 11}}{\text{Fig. 12}};$	-	0.1	0.5	μs

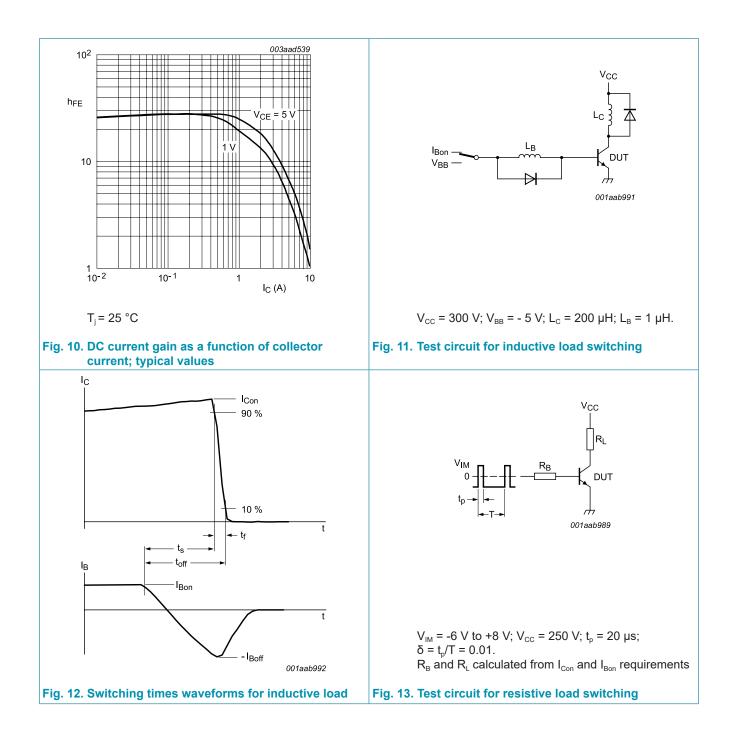
[1] Measured with half-sine wave voltage (curve tracer).

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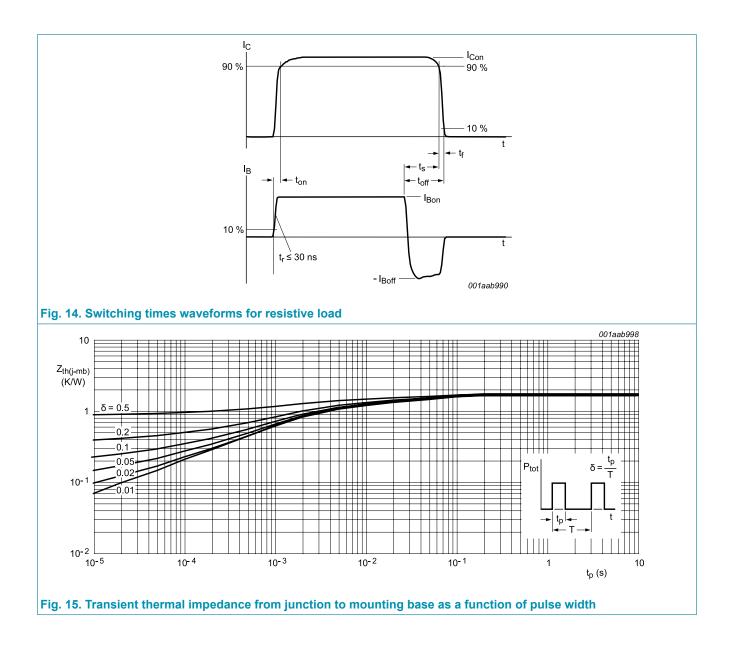
NPN power transistor with integrated diode

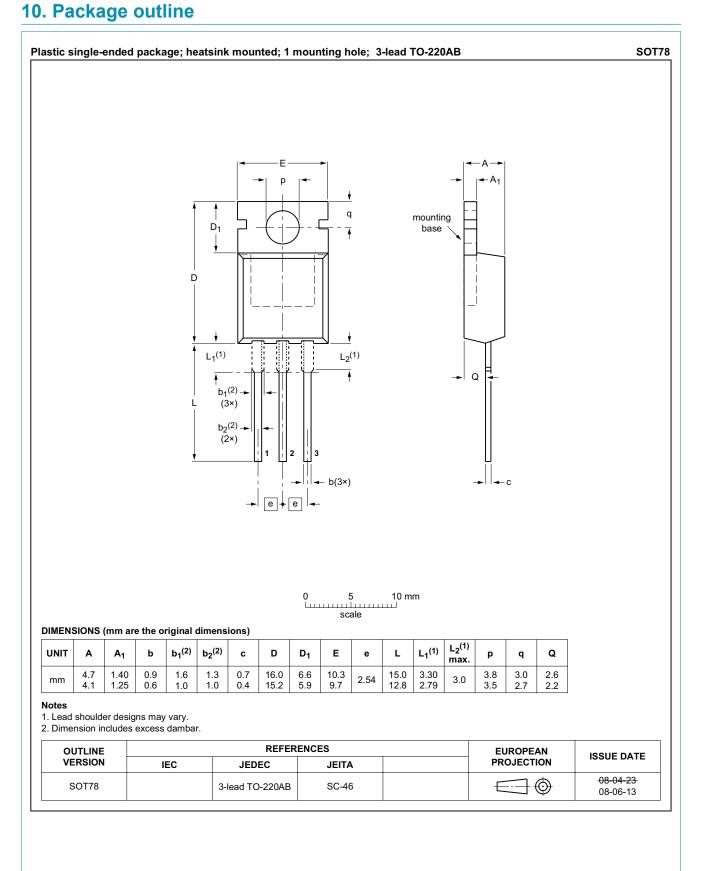


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NPN power transistor with integrated diode

PHD13005





11. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHD13005 v.3	20180330	Product data sheet	-	PHD13005 v.2
Modifications:	Change from NXP version to WeEr	version		
PHD13005 v.2	20100729	Product data sheet	-	PHD13005 v.1
Modifications:	Various changes to content.			
PHD13005 v.1	20100520	Product data sheet	-	-

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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